

FEE TRANSMITTAL

Electronic Version v08

Stylesheet Version v08.0

Title of Invention	STRUCTURE AND METHOD OF MAKING STRAINED SEMICONDUCTOR CMOS TRANSISTORS HAVING LATTICE-MISMATCHED SOURCE AND DRAIN REGIONS
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Application Number :

Date :

First Named Applicant: Huajie Chen

Attorney Docket Number: FIS920030199US1

TOTAL FEE AUTHORIZED \$ 1006

Patent fees are subject to annual revisions on or about October 1st of each year.

Filing as large entity

BASIC FILING FEE

Fee Description	Fee Code	Amount \$	Fee Paid \$
Utility Filing Fee	1001	750	750
Subtotal For Basic Filing Fees: \$ 750			

EXTRA CLAIM FEES

Fee Description	Extra Claim	Fee Code	Amount \$	Fee Paid \$
Total Claims : 32	12	1202	18	216
Independent Claims : 3	0	1201	84	0
Subtotal For Extra Claims Fees: \$ 216				

ASSIGNMENT FEES

Fee Description	Property Number	Quantity	Fee Code	Amount \$	Fee Paid \$
Recording Each Patent Assignment Per Property Fee	00000000	1	8021	40	40
Subtotal For Additional Fees: \$40					

AUTHORIZED BILLING INFORMATION

The commissioner is hereby authorized to charge indicated fees and credit any overpayments to:

Deposit account number: 090458

Deposit name: International Business Machines Corporation

Deposit authorized name: H. Daniel Schnurmann

Signature: H. Daniel Schnurman

Date (YYYYMMDD): 2003-08-04

Charge Any Additional Fee Required Under 37 C.F.R. Sections 1.16 and 1.17.